

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Hameed A. NASEEM et al.

Appln. No.:

Filed: Herewith

For: METHOD OF DOPING SILICON, METAL DOPED SILICON,  
METHOD OF MAKING SOLAR CELLS AND SOLAR CELLS

\* \* \*

INFORMATION DISCLOSURE STATEMENT

Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

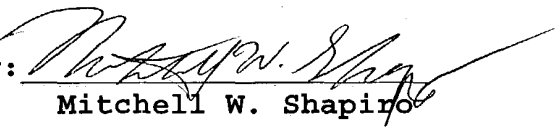
Applicants wish to make record the documents cited in  
predecessor Application Nos. 10/029,859 filed December 31,  
2001 and 08/855,229 filed May 13, 1997, whether cited by  
Applicants or by the Patent Office. The documents are  
listed on the attached Form-1449.

Respectfully submitted,

MWS:lmb:jb

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July 14, 2003

<b>FORM PTO-1449</b>				Atty. Docket No. <b>A-9508B</b>		Appln. No.	
<b><u>LIST OF DOCUMENTS CITED BY APPLICANT</u></b>							
				Applicant <b>Hameed A. NASEEM et al.</b>			
				Filing Date <b>HEREWITH</b>		Group	
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	AL	WO97/13280	04/10/97	WIPO			
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	AM	HAQUE, M. et al., "Hydrogenated Amorphous Silicon/Aluminum Interaction at Low Temperatures," <u>Materials Research Society Symposium</u> , Vol. 258, 1992, pp. 1037-1042.					
	AN	HAQUE, M. S. et al., "Degradation and Failure Mechanisms of a-Si:H Solar Cells with Aluminum Contacts," <u>IEEE First ECPEC</u> , 1994, pp. 642-645.					
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Examiner				Date Considered			
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							

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	AW	Lathrop, J.W., "Accelerated Stress Testing of a-Si:H Cells," <u>Proc. 2nd Int. Photovoltaic Science and Engineering Conference</u> , Beijing, China, August 1986, pp. 386-389.					
	AX	Delahoy, A.E., "Amorphous Silicon-Aluminum Materials," <u>Research on High Efficiency Single Junction Monolithic Thin Film a-Si Solar Cells</u> , Nov. 1985, pp. 13-20.					
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